

isc Silicon NPN Darlington Power Transistor

TIP130

DESCRIPTION

- High DC Current Gain-
- : h_{FE} = 1000(Min)@ I_C= 4A
- Collector-Emitter Sustaining Voltage-: V_{CEO(SUS)} = 60V(Min)
- Low Collector-Emitter Saturation Voltage-: V_{CE(sat)} = 2.0V(Max)@ I_C= 4A
- Complement to Type TIP135
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Designed for general-purpose amplifier and low-speed switching applications

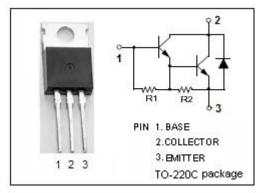
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

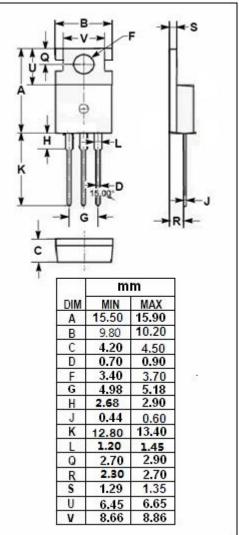
SYMBOL	PARAMETER	VALUE	UNIT			
V _{CBO}	Collector-Base Voltage	60	V			
V _{CEO}	Collector-Emitter Voltage	60	V			
V _{EBO}	Emitter-Base Voltage	5	V			
Ic	Collector Current-Continuous	8	А			
Ісм	Collector Current-Peak	12	А			
I _B	Base Current- Continuous	0.3	А			
Pc	Collector Power Dissipation @Tc=25°C	70	24/			
	Collector Power Dissipation @Ta=25℃	2	W			
Tj	unction Temperature 150		°C			
T _{stg}	Storage Temperature Range	-65~150	°C			

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	1.785	°C/W
Rth j-a	Thermal Resistance, Junction to Ambient	63.5	°C/W

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ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 30mA, I _B = 0	60		V
VCE(sat)-1	Collector-Emitter Saturation Voltage	I _C = 4A; I _B = 16mA		2.0	V
VCE(sat)-2	Collector-Emitter Saturation Voltage	I _C = 6A, I _B = 30mA		3.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 4A; V _{CE} = 4V		2.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 60V, I _E = 0		0.2	mA
I _{CEO}	Collector Cutoff Current	V _{CE} = 30V, I _B = 0		0.5	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0		5	mA
hfe-1	DC Current Gain	Ic= 1A; V _{CE} = 4V	500		
h _{FE-2}	DC Current Gain	I _C = 4A; V _{CE} = 4V	1000	15000	

NOTICE:

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